

C1206C821GBGACTU

Aliases (C1206C821GBGAC7800) SMD Comm C0G HV, Ceramic, 820 pF, 2%, 630 VDC, C0G, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1206, 1.5 mm



General Information	
Series	SMD Comm COG HV
Style	SMD Chip
Description	SMD, MLCC, Ultra-Stable, Low Loss, Class I
Features	Ultra-Stable, Low Loss, Class I
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Typical Component Weight	30 mg
Shelf Life	78 Weeks
MSL	1

Dimensions	
Chip Size	1206
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
т	1.2mm +/-0.15mm
S	1.5mm MIN
В	0.5mm +/-0.25mm

Packaging SpecificationsPackagingT&R, 180mm, Plastic TapePackaging Quantity2500

Specifications	
Capacitance	820 pF
Measurement Condition	1 MHz 1.0Vrms
Tolerance	2%
Voltage DC	630 VDC
Dielectric Withstanding Voltage	945 VDC
Temperature Range	-55/+125°C
Temp. Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1MegaHz 1.0Vrms
Dissipation Factor	0.1% 1 MHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	100 GOhms

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